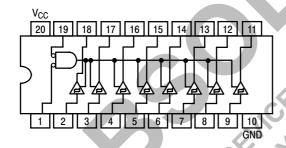
Octal Buffer/Line Driver with 3-State Outputs

The SN74LS541 is an octal buffer and line driver with the same functions as the LS241, but with pinouts on the opposite side of the package.

This device type is designed to be used as a memory address driver, clock driver and bus-oriented transmitter/receiver. This device is especially useful as output ports for the microprocessors, allowing ease of layout and greater PC board density.

- Hysteresis at Inputs to Improve Noise Margin
- PNP Inputs Reduce Loading
- 3-State Outputs Drive Bus Lines
- Inputs and Outputs Opposite Side of Package, Allowing Easier Interface to Microprocessors
- Input Clamp Diodes Limit High-Speed Termination Effects

LOGIC AND CONNECTION DIAGRAM DIP (TOP VIEW)



GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Тур	Max	Unit
V _{CC}	Supply Voltage	4.75	5.0	5.25	V
T _A	Operating Ambient Temperature Range	0	25	70	°C
I _{OH}	Output Current - High			-15	mA
I _{OL}	Output Current – Low	6.		24	mA



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LOW POWER SCHOTTKY

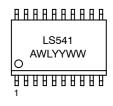
MARKING DIAGRAMS



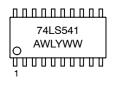
CASE 738

SN74LS541N AWLYYWW









A = Assembly Location WL = Wafer Lot Y, YY = Year

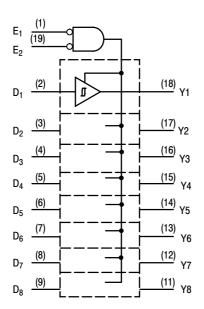
WW = Work Week

ORDERING INFORMATION

Device	Package	Shipping
SN74LS541N	PDIP-20	1440 Units/Box
SN74LS541DW	SOIC-WIDE	38 Units/Rail
SN74LS541DWR2	SOIC-WIDE	2500/Tape & Reel
SN74LS541M	SOEIAJ-20	See Note 1
SN74LS541MEL	SOEIAJ-20	See Note 1

 For ordering information on the EIAJ version of the SOIC package, please contact your local ON Semiconductor representative.

BLOCK DIAGRAM



IN	PUTS	3	OUTPUTS		
E ₁	E ₂	D	LS540	LS541	
L	L	Н	L	Η	
Н	X	Х	Z	Z	
Χ	Н	Х	Z	Z	
┙	┙	L	Ι	L	

L = LOW Voltage Level

H = HIGH Voltage Level

X = Immaterial

Z = High Impedance

DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

		Limits			(°0 '		
Symbol	Parameter	Min	Тур	Max	Unit	Tes	t Conditions
V _{IH}	Input HIGH Voltage	2.0			>	Guaranteed Input HIGH Voltage for All Inputs	
V _{IL}	Input LOW Voltage			0.8	٧	Guaranteed Input LOW Voltage for All Inputs	
V _{IK}	Input Clamp Diode Voltage		-0.65	-1.5	V	V _{CC} = MIN, I _{IN} = -	- 18 mA
V	Output HICH Voltage	2.4	3.4	10.	V	V _{CC} = MIN, I _{OH} =	-3.0 mA
V _{OH}	Output HIGH Voltage		1		V	$V_{CC} = MIN$, $I_{OH} = MAX$, $V_{IL} = 0.5 V$	
.,			0.25	0.4	V	I _{OL} = 12 mA	V _{CC} = V _{CC} MIN,
V _{OL}	Output LOW Voltage		0.35	0.5	V	I _{OL} = 24 mA	V _{IN} = V _{IL} or V _{IH} per Truth Table
$V_{T+}-V_{T-}$	Hysteresis	0.2	0.4		V	V _{CC} = MIN	
l _{OZH}	Output Off Current HIGH			20	μΑ	V _{CC} = MAX, V _{OUT} = 2.7 V	
l _{OZL}	Output Off Current LOW			-20	μΑ	V _{CC} = MAX, V _{OU}	_T = 0.4 V
l	Input HIGH Current			20	μΑ	V _{CC} = MAX, V _{IN} =	= 2.7 V
I _{IH}	input nigh Current			0.1	mA	V _{CC} = MAX, V _{IN} =	= 7.0 V
I _{IL}	Input LOW Current			-0.2	mA	V _{CC} = MAX, V _{IN} =	= 0.4 V
los	Short Circuit Current (Note 1)	-40		-225	mA	V _{CC} = MAX	
	Power Supply Current Total, Output HIGH			32	mA		
Icc	Total, Output LOW			52	mA	V _{CC} = MAX	
	Total Output 3-State			55	mA		

^{1.} Not more than one output should be shorted at a time, nor for more than 1 second.

AC CHARACTERISTICS $(T_A = 25^{\circ}C)$

			Limits			
Symbol	Parameter	Min	Тур	Max	Unit	Test Conditions
t _{PLH}	Propagation Delay,		12	15		
t _{PHL}	Data to Output		12	18	ns	V - 5 V
t _{PZH}	Output Enable Time to HIGH Level		15	32	ns	V_{CC} = 5.0 V C_L = 45 pF R_L = 667 Ω
t _{PZL}	Output Enable Time to LOW Level		20	38	ns	_
t _{PHZ}	Output Disable Time to HIGH Level		10	18	ns	0 50.5
t _{PLZ}	Output Disable Time to LOW Level		15	29	ns	C _L = 5.0 pF

AC WAVEFORMS

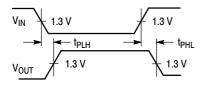


Figure 1.

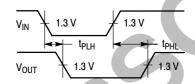


Figure 2.

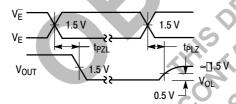


Figure 3.

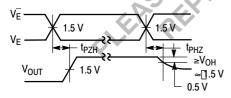
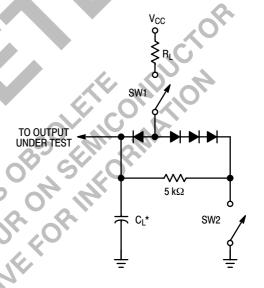


Figure 4.



SWITCH POSITIONS

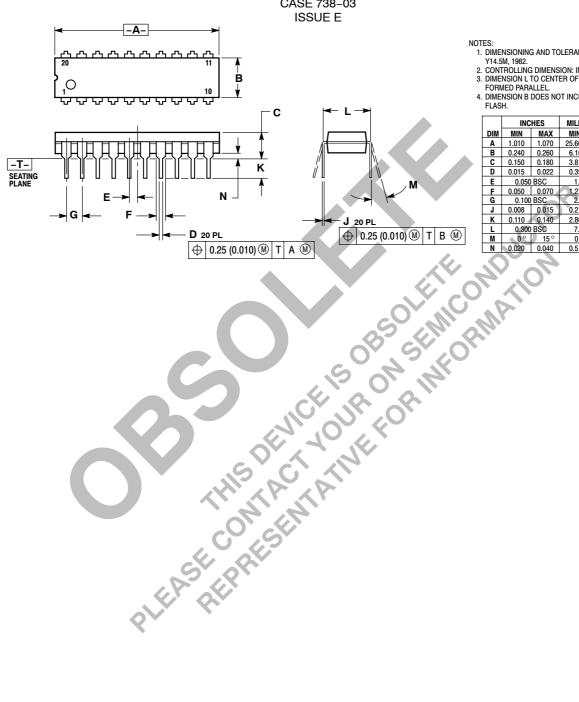
SYMBOL	SW1	SW2
t _{PZH}	Open	Closed
t _{PZL}	Closed	Open
t _{PLZ}	Closed	Closed
t _{PHZ}	Closed	Closed

Figure 5.

PACKAGE DIMENSIONS

N SUFFIX

PLASTIC PACKAGE CASE 738-03



NOTES:

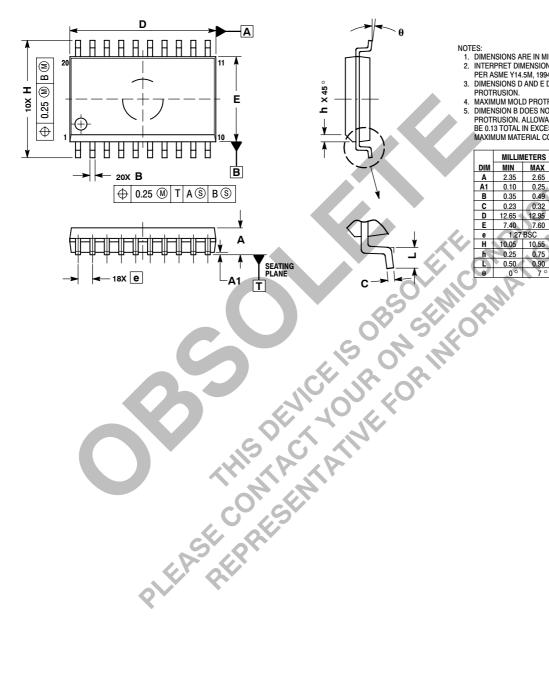
- 1. DIMENSIONING AND TOLERANCING PER ANSI

- 1. DIMENSIONING AND TOLERANCING FER AI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH. 3. DIMENSION L TO CENTER OF LEAD WHEN FORMED PARALLEL 4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.

	INC	HES	MILLIN	ETERS	
DIM	MIN	MIN MAX		MAX	
Α	1.010	1.070	25.66	27.17	
В	0.240	0.260	6.10	6.60	
С	0.150	0.180	3.81	4.57	
D	0.015	0.022	0.39	0.55	
E	0.050	BSC	1.27 BSC		
F	0.050	0.070	1.27	1.77	
G	0.100	BSC	2.54 BSC		
J	0.008	0.015	0.21	0.38	
K	0.110	0.140	2.80	3.55	
L	0.300	0.300 BSC		BSC	
M	0°	15°	0°	15°	
N	0.020	0.040	0.51	1.01	

PACKAGE DIMENSIONS

D SUFFIX PLASTIC SOIC PACKAGE CASE 751D-05 **ISSUE F**



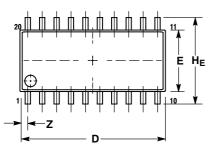
- NOTES:
 1. DIMENSIONS ARE IN MILLIMETERS.
 2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.
- DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSION.
- MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
 DIMENSION B DOES NOT INCLUDE DAMBAR
 PROTRUSION. ALLOWABLE PROTRUSION SHALL
 BE 0.13 TOTAL IN EXCESS OF B DIMENSION AT MAXIMUM MATERIAL CONDITION.

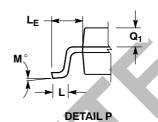
	MILLIMETERS				
DIM	MIN	MAX			
Α	2.35	2.65			
A1	0.10	0.25			
В	0.35	0.49			
С	0.23	0.32			
D	12.65	12.95			
Е	7.40	7.60			
е	1.27	BSC			
H ⁴	10.05	10.55			
h	0.25	0.75			
(L)	0.50	0.90			
A	0 0	70			

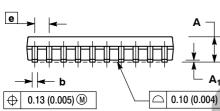
PACKAGE DIMENSIONS

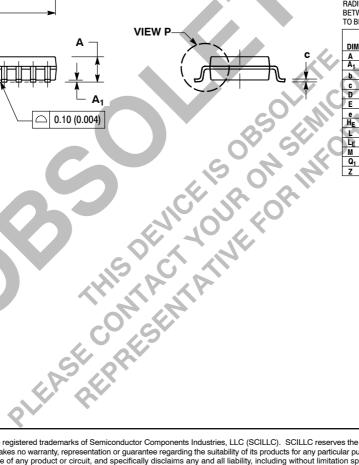
M SUFFIX

SOEIAJ PACKAGE CASE 967-01 ISSUE O









NOTES

- DIMENSIONING AND TOLERANCING PER ANSI
 Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: MILLIMETER.
- DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS AND ARE MEASURED AT THE PARTING LINE. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.15 (0.006) PER SIDE
- 4. TERMINAL NUMBERS ARE SHOWN FOR
- REFERENCE ONLY.

 5. THE LEAD WIDTH DIMENSION (b) DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE LEAD WIDTH DIMENSION AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT, MINIMUM SPACE BETWEEN PROTRUSIONS AND ADJACENT LEAD TO BE 0.46 (0.018).

	MILLIÑ	IETERS	INC	HES	
DIM	MIN	MAX	MIN	MAX	
Α		2.05		0.081	
Α∟	0.05	0.20	0.002	0.008	
b	0.35	0.50	0.014	0.020	
C	0.18	0.27	0.007	0.011	
D	12.35	12.80	0.486	0.504	
E	5.10	5.45	0.201	0.215	
e 👝	1.27	BSC	0.050 BSC		
HE	7.40	8.20	0.291	0.323	
	0.50	0.85	0.020	0.033	
LE	1.10	1.50	0.043	0.059	
M	0 °	10 °	0 °	10 °	
Q_1	0.70	0.90	0.028	0.035	
Z		0.81		0.032	

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